

Test Qualification Plan

1. SCM Correlation Data Gathering

- Loop 4 bin1 units x30
- Run 100 bin1 units on handler
- Serialize and test 10 bin1 units
- Serialize and test 5 reject units

2. Ship correlation package from SCM to SCC

3. SCC Correlation Data Gathering

- Loop 4 bin1 units x30
- Run 100 bin1 units on handler
- Test 10 already serialized bin1
- Test 5 already serialized rejects

4. SCM/SCC send data to ADGT for Data Crunching and Analysis

5. CorL8 Analysis of x30 loop /100 units handler data

- X30 loop must pass Mean Shift, Sigma Spread and CPK criteria
- 100 Bin1 Correlation units must pass Mean Shift, Sigma Spread and CPK criteria
- 10 serialized units must pass bin1 both in SCC and in SCM
- 5 serialized rejects must fail the same parameter for both SCC and SCM

6. Correlation Data Approval

- For TRB movement to Available with Condition

7. Validation lot run handled by SCC

Note: CorL8 is ADI data analysis tool.



Reject Correlation		
Unit	SCM	SCC
1	TnumX: XXXXX	TnumX: XXXXX
...	TnumX: XXXXX	TnumX: XXXXX
5	TnumX: XXXXX	TnumX: XXXXX

Bin1 Correlation		
Unit	SCM	SCC
1	Pass	Pass
...	Pass	Pass
10	Pass	Pass

Correlation Test Criteria(TST00137)	
% Mean Shift Criteria	$((\text{SCM_mean} - \text{SCC_Mean}) / (\text{Upper_Limit} - \text{Lower_Limit})) \times 100 < 5$
Sigma Spread Criteria	$(\text{SCC_Sigma} / \text{SCM_Sigma}) < 1.300000$
Cpk Criteria	If Cpk to the test limits is >10, then test given automatically PASS

Test Qualification estimated Timeline

Devices	Oct, 2013 to Nov, 2013	Dec, 2013 to Apr, 2014	May, 2014
SCM Correlation Data Gathering&Shipment	PLANNED	PLANNED	
SCC Correlation Data Gathering		PLANNED	
Data Review and Approved by ADGT		PLANNED	
Validation Run/TRB Closure		PLANNED	PLANNED

 PLANNED
 ACTUAL/ADJUSTED

Reliability Qualification Plan for LFCSP Package at STATS ChipPAC China (SCC)

QUALIFICATION PLAN			
Test	Conditions	Sample Size	Expected Completion Date
Highly Accelerated Stress Test (HAST)*	JEDEC <i>JESD22-A110</i>	3 x 77	April 2014
Temperature Cycle (TC)*	JEDEC <i>JESD22-A104</i>	3 x 77	April 2014
Autoclave (AC)*	JEDEC <i>JESD22-A102</i>	3 x 77	April 2014
Solder Heat Resistance (SHR)*	JEDEC/IPC <i>J-STD-020</i>	3 x 11	April 2014
High Temperature Storage Life (HTSL)	JEDEC <i>JESD22-A103</i>	1 x 77	April 2014
Field Induced Charged Device Model (FICDM)	JEDEC <i>JESD22-C101</i>	3/Voltage	April 2014

*Preconditioned per JEDEC/IPC J-STD-020